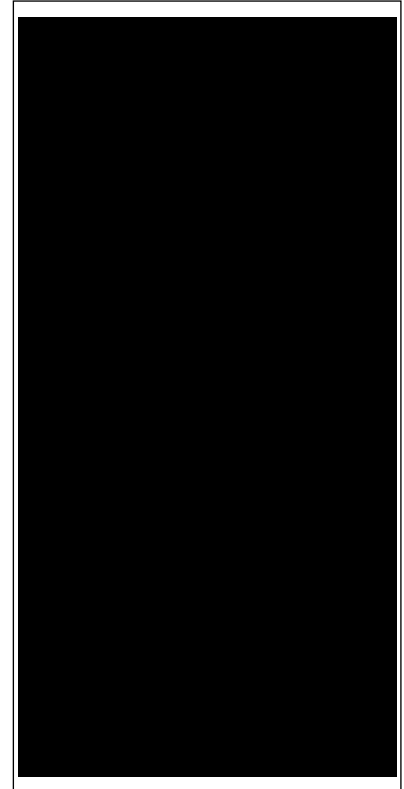




The JST24F-800BW triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. JST24F-800BW snubberless triac is especially recommended for use on inductive loads. By using an external plastic package, JST24F-800BW provides a rated insulation voltage of 2000 VRMS, complying with UL standards (File ref: E252906). Package TO-220F is RoHS compliant.

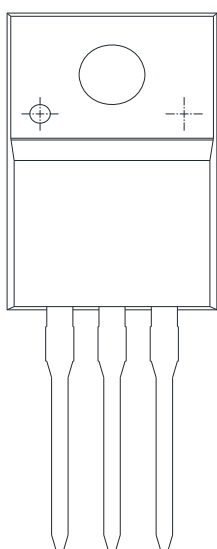


| Symbol | Value | Unit |
|-------------------|----------|------|
| $I_{T(RMS)}$ | 25 | A |
| V_{DRM}/V_{RRM} | 800 | V |
| $I_{GT} / /$ | 50/50/50 | mA |

| | | | |
|--|--------------|---------|------------------------|
| Storage junction temperature range | T_{stg} | -40-150 | |
| Operating junction temperature range | T_j | -40-125 | |
| Repetitive peak off-state voltage ($T_j=25^\circ\text{C}$) | V_{DRM} | 800 | V |
| Repetitive peak reverse voltage ($T_j=25^\circ\text{C}$) | V_{RRM} | 800 | V |
| RMS on-state current ($T_c = 72^\circ\text{C}$) | $I_{T(RMS)}$ | 25 | A |
| Non repetitive surge peak on-state current (full cycle, $t_p=20\text{ms}$, $T_j=25^\circ\text{C}$) | I_{TSM} | 250 | A |
| Non repetitive surge peak on-state current (full cycle, $t_p=16.6\text{ms}$, $T_j=25^\circ\text{C}$) | | 275 | |
| I^2t value for fusing ($t_p=10\text{ms}$, $T_j=25^\circ\text{C}$) | I^2t | 340 | A^2s |
| Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$, $f=100\text{Hz}$, $T_j=125^\circ\text{C}$) | di/dt | 100 | $\text{A}/\mu\text{s}$ |
| Peak gate current ($t_p=20\mu\text{s}$, $T_j=125^\circ\text{C}$) | I_{GM} | 4 | A |
| Average gate power dissipation ($T_j=125^\circ\text{C}$) | $P_{G(AV)}$ | 0.5 | W |



| | | | | | |
|-----------------------------------|-----------|------------------|----------------|---|----------------|
| J | ST | 24 | F | -800 | BW |
| JieJie Microelectronics Co., Ltd. | Triacs | $I_{T(RMS)}:25A$ | F:TO-220F(Ins) | 800:V _{DRM} /V _{RRM} 800V | BW:IGT1-3 50mA |



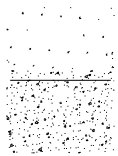


Maximum power dissipation versus RMS
on-state current

RMS on-state current versus case
temperature







1

